

KSD1222

Power Amplifier Applications High DC Current Gain

- Low Collector-Emitter Saturation Voltage
- Built in a Damper Diode at E-C
- Darlington TR
- Complement to KSB907



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V _{CEO}	Collector-Emitter Voltage	40	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	3	Α
I _B	Base Current	0.3	Α
P _C	Collector Dissipation (T _C =25°C)	15	W
	Collector Dissipation (T _a =25°C)	1	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 25mA, I_B = 0$	40			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 60V, I_{E} = 0$			20	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			2.5	mA
h _{FE1} h _{FE2}	DC Current Gain	$V_{CE} = 2V, I_{C} = 1A$ $V_{CE} = 2V, I_{C} = 3A$	2000 1000			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 2A$, $I_B = 4mA$			1.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_{C} = 2A, I_{B} = 4mA$			2	V
t _{ON}	Turn On Time	$V_{CC} = 30V, I_{C} = 3A$		0.1		μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 6mA$		1		μs
t _F	Fall Time	$R_L = 10\Omega$		0.2		μs

Typical Characteristics

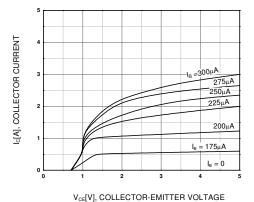


Figure 1. Static Characteristic

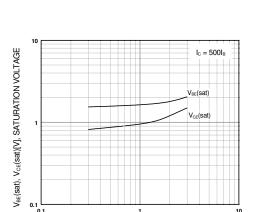


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

I_C[A], COLLECTOR CURRENT

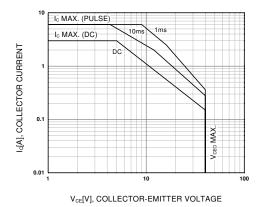


Figure 5. Safe Operating Area

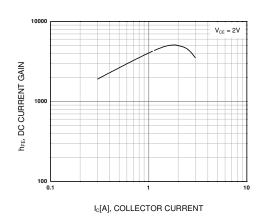


Figure 2. DC current Gain

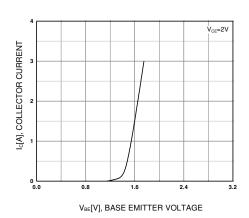


Figure 4. Base-Emitter On Voltage

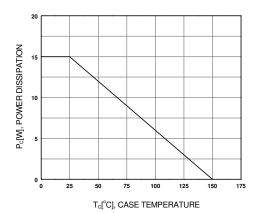
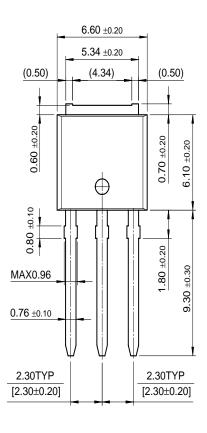


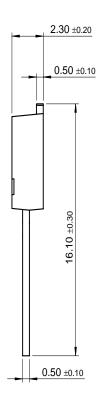
Figure 6. Power Derating

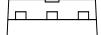
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Package Demensions

I-PAK







Dimensions in Millimeters

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